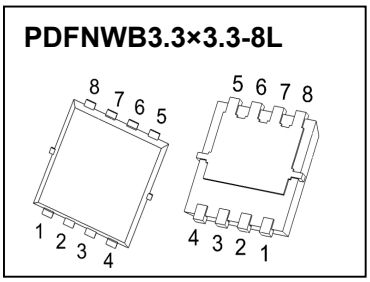
SZCJ

Shenzhen Changji Semiconductor Co., LTD.

PDFNWB3.3×3.3-8L Plastic-Encapsulate MOSFET

CJAB25N04A N-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$TYP	I_D
40V	6.5mΩ@10V	25A
	8.4mΩ@4.5V	



DESCRIPTION

The CJAB25N04A uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

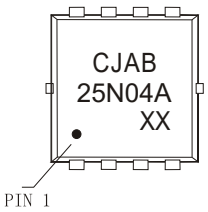
FEATURES

- High Power and current handing capability
- Load switch
- High density cell design for ultra low $R_{DS(ON)}$
- Lead free product is acquired
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

APPLICATIONS

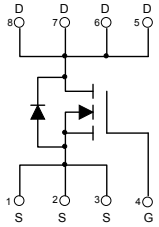
- SMPS and general purpose applications
- Hard switched and high frequency circuits
- Uninterruptible Power Supply
- Power management

MARKING



CJAB25N04A = Part No.
Solid dot = Pin1 indicator.
XX = Code.

EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D ①	25	A
Pulsed Drain Current	I_{DM} ①②	100	A
Single Pulsed Avalanche Energy	E_{AS} ③	137	mJ
Power Dissipation	P_D ①	50	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$ ⑤	83.3	℃/W
Thermal Resistance from Junction to Case	$R_{\theta JC}$ ①	2.5	℃/W
Operating Junction and Storage Temperature Range	T_J ,T_{STG}	-55~+150	℃

MOSFET ELECTRICAL CHARACTERISTICS

T_J=25℃ unless otherwise specified

Parameter	Symbol	Test Condition		Min	Typ	Max	Unit
Off characteristics							
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =250μA		40	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS} =40V, V_{GS} =0V	T_J =25℃	-	-	1.0	μA
			T_J =125℃	-	-	100	
Gate-body leakage current	I_{GSS}	V_{DS} =0V, V_{GS} =±20V		-	-	±100	nA
On characteristics ④							
Gate-threshold voltage	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =250μA		1.0	1.8	2.5	V
Static drain-source on-sate resistance	$R_{DS(on)}$	V_{GS} =10V, I_D =10A			6.6	8.5	mΩ
		V_{GS} =4.5V, I_D =10A			8.5	12	mΩ
Dynamic characteristics							
Input capacitance	C_{iss}	V_{DS} =20V,V_{GS} =0V, f =1MHz		-	2893	-	pF
Output capacitance	C_{oss}			-	189	-	
Reverse transfer capacitance	C_{rss}			-	154	-	
Gate resistance	R_g	f =1MHz		-	3.0	-	Ω
Switching characteristics							
Total gate charge	Q_g	V_{GS}=4.5V, V_{DS}=20V, I_D=10A		-	24	-	nC
Total gate charge	Q_g	V_{GS}=10V, V_{DS}=20V, I_D=10A		-	51	-	
Gate-source charge	Q_{gs}			-	7.3	-	
Gate-drain charge	Q_{gd}			-	8.2	-	
Turn-on delay time	$t_{d(on)}$	V_{DS}=20V, VGS=10V, R_L=2.7Ω , Rg=10Ω		-	40	-	ns
Turn-on rise time	t_r			-	41	-	
Turn-off delay time	$t_{d(off)}$			-	402	-	
Turn-off fall time	t_f			-	116	-	
Drain-Source Diode Characteristics							
Drain-source diode forward voltage	V_{SD} ④	V_{GS} =0V, I_S=10A		-	-	1.2	V
Continuous drain-source diode forward current	I_S ①			-	-	25	A
Pulsed drain-source diode forward current	I_{SM} ①②			-	-	100	A
Reverse recovery time	trr	di_S/dt = 100A/μs, I_S = 13A, V_{DD} = 30V		-	23	-	ns
Reverse recovery charge	Qrr			-	13	-	nC

Notes:

1.T_C=25℃.

2.Limited only by maximum temperature allowed.

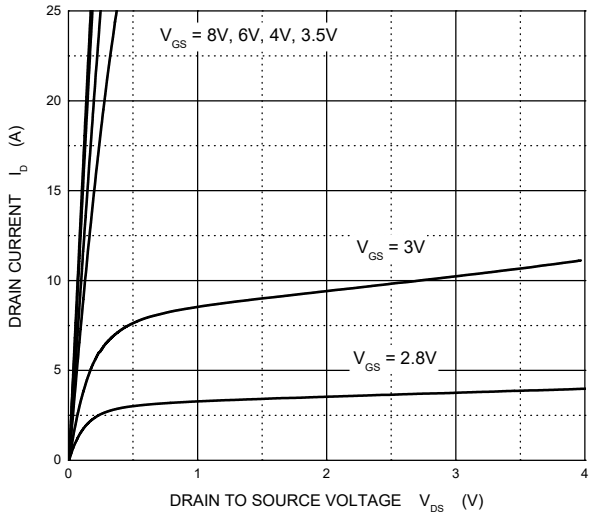
3.V_{DD}=20V,V_{GS}=10V, L=0.5mH, Rg=25Ω Starting T_J= 25℃.

4.Pulse Test : Pulse Width≤380μs, duty cycle ≤2%.

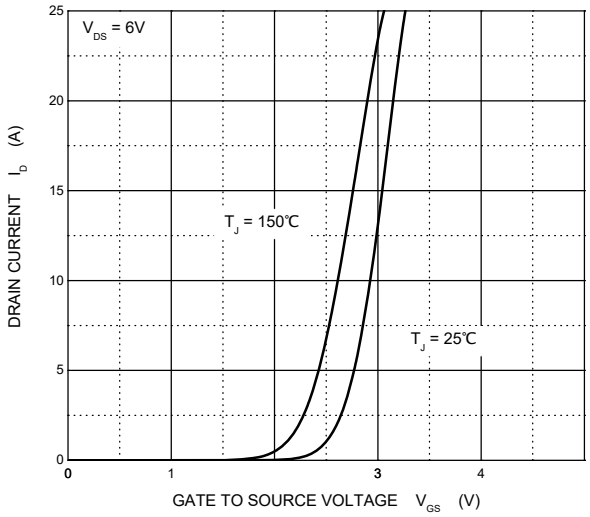
5.Device mounted on 1 in^2 FR-4 board with 2oz. single-sided Copper, in a still air environment with T_A=25 ℃.

Typical Characteristics (T_J = 25℃, unless otherwise specified)

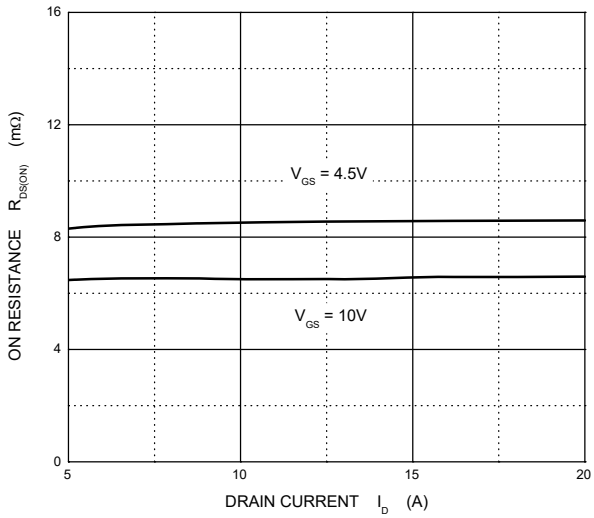
Output Characteristics



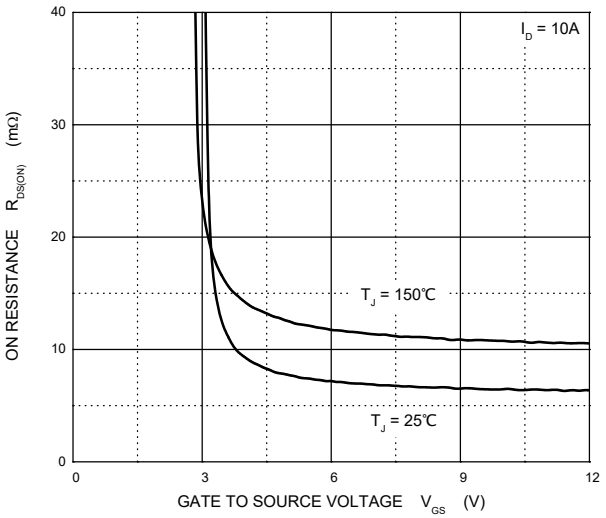
Transfer Characteristics



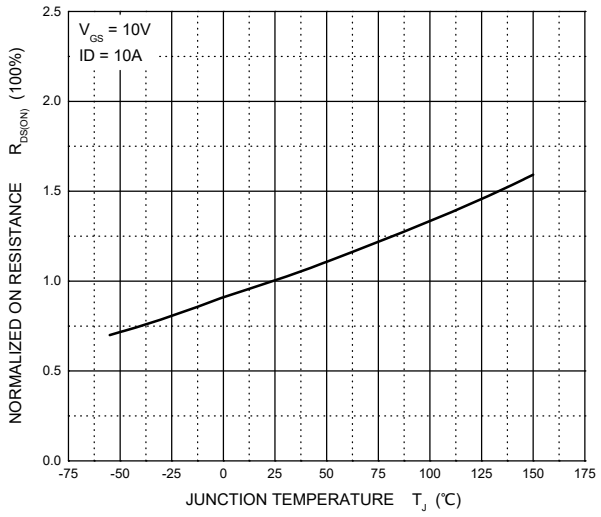
On Resistance vs. Drain Current



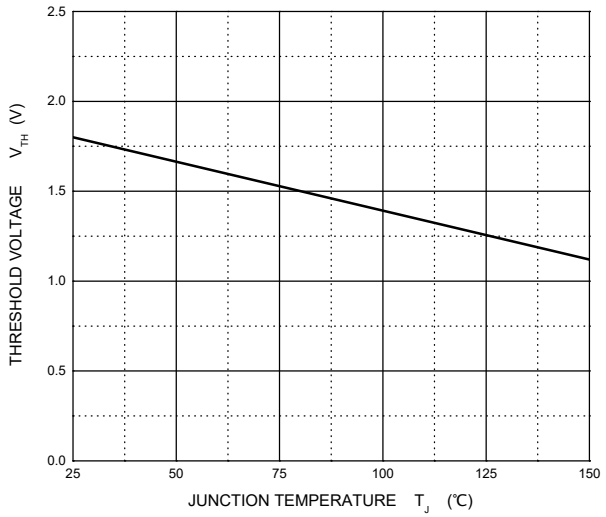
On Resistance vs. Gate-Source Bias



On Resistance vs. Junction Temperature

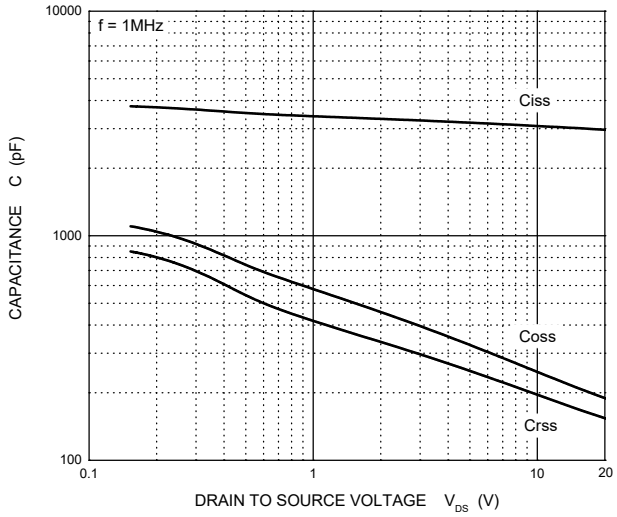


Gate-Source Threshold Voltage

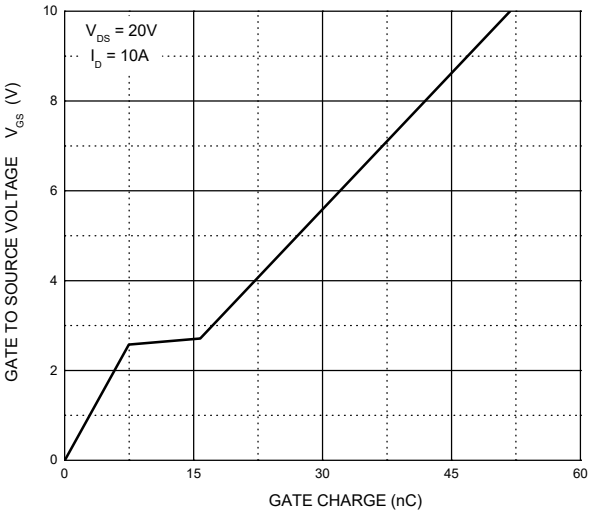


Typical Characteristics (T_J = 25℃, unless otherwise specified)

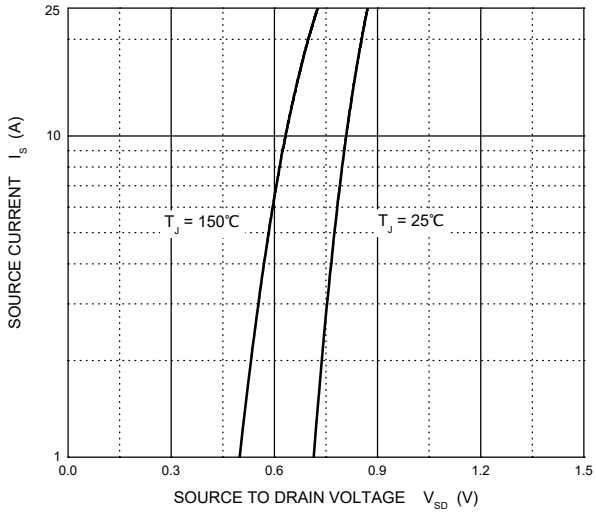
Typical Capacitances



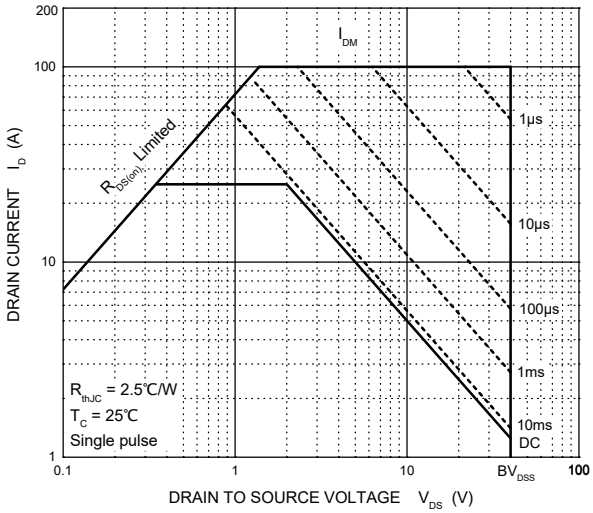
Gate Charge



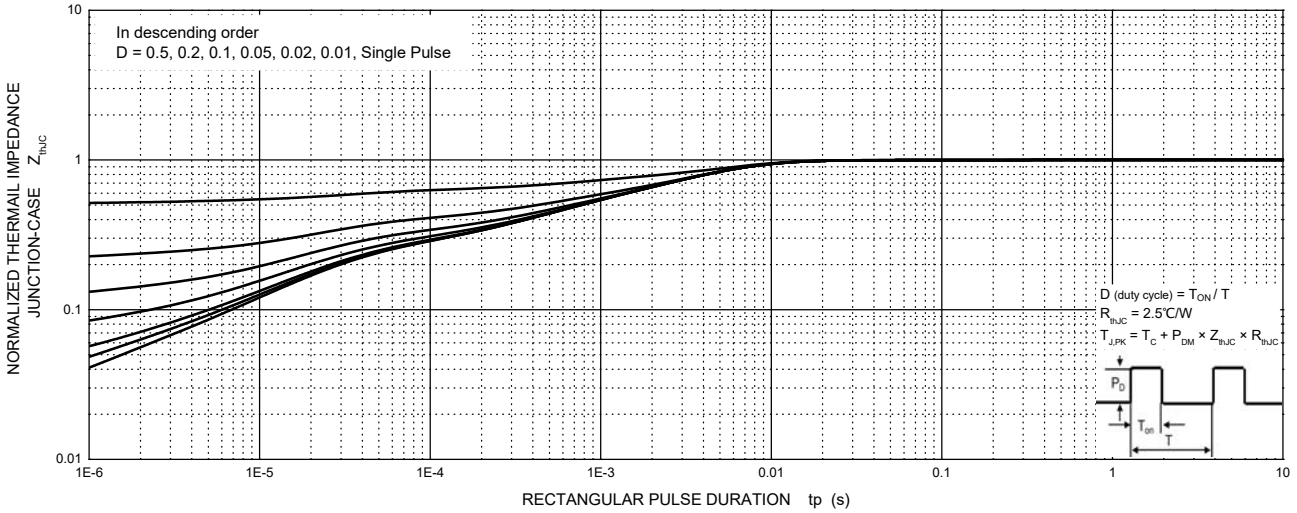
Source-Drain Diode Forward Characteristics



Maximum Safe Operating Area



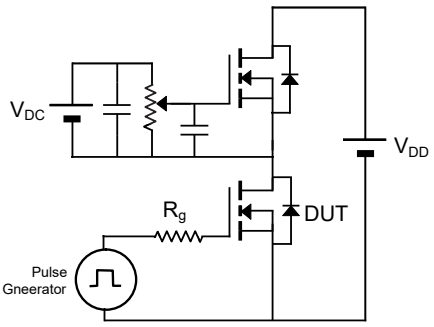
Transient Thermal Impedance, Junction-Case

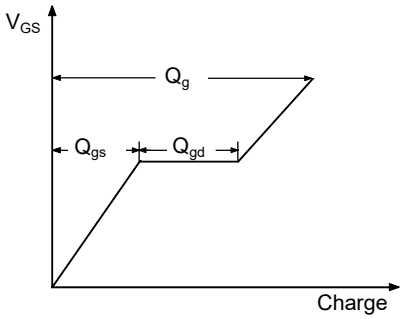


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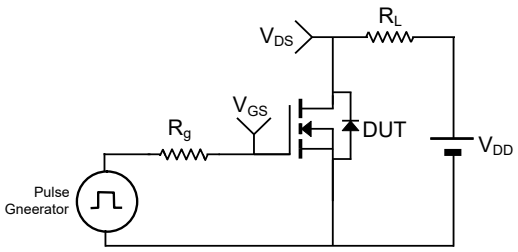
TEST CIRCUIT AND WAVEFOMRS

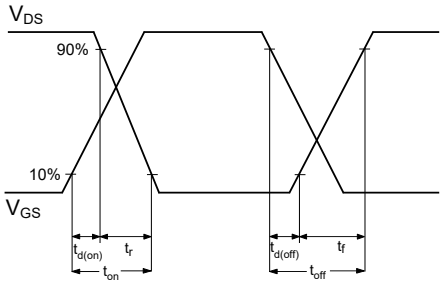
Gate Charge



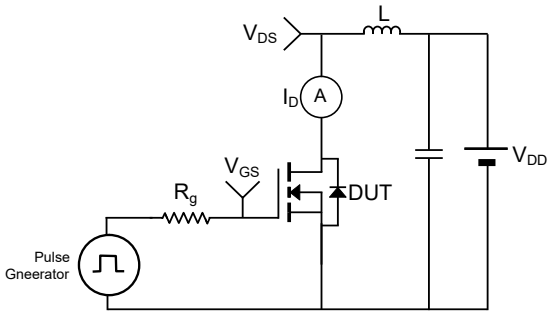


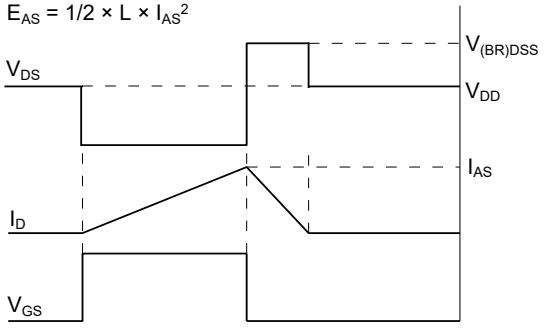
Resistive Load Switching Time



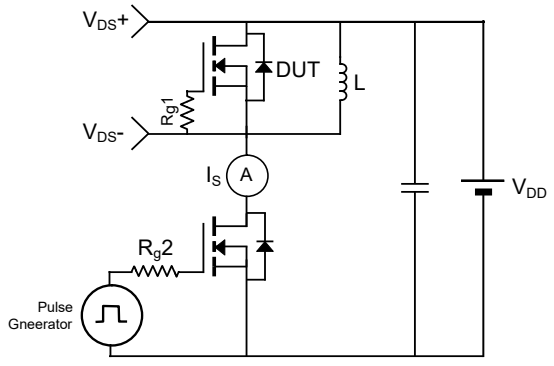


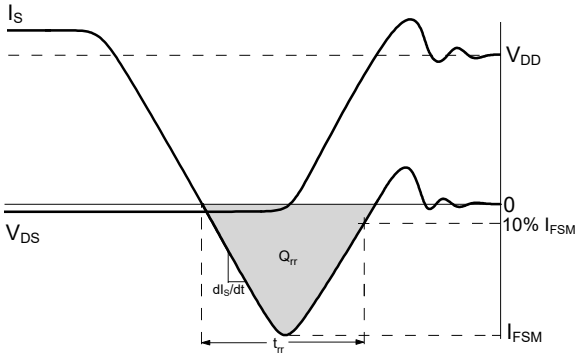
Un-clamped Inductive Load Switching



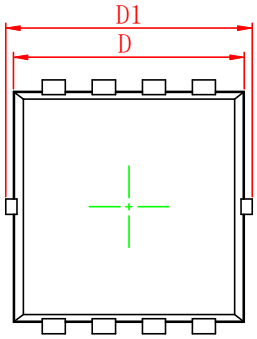


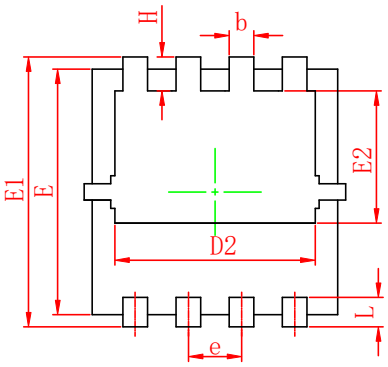
Drain-Source Body Diode Reverse Recovery

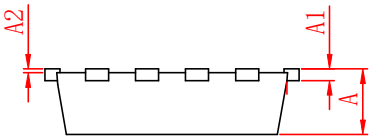




PDFNWB3.3×3.3-8L PACKAGE OUTLINE DIMENSIONS



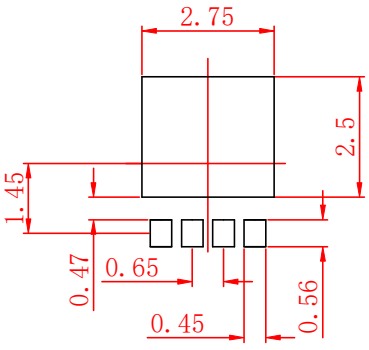




Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.65	0.90	0.026	0.035
A1	0.15 REF.		0.006 REF.	
A2	0~0.05		0~0.002	
D	2.90	3.20	0.114	0.126
D1	3.00	3.40	0.118	0.134
D2	2.60	2.90	0.102	0.114
E	2.90	3.20	0.114	0.126
E1	3.00	3.40	0.118	0.134
E2	1.70	2.10	0.067	0.083
b	0.20	0.40	0.008	0.016
e	0.65 BSC.		0.026 BSC.	
L	0.20	0.50	0.008	0.020
H	0.32	0.52	0.012	0.020

Notes：
1 Dimensions exclusive of mold gate burrs.
2 Dimensions exclusive of mold flash and cutting burrs.

PDFNWB3.3×3.3-8L Suggested Pad Layout

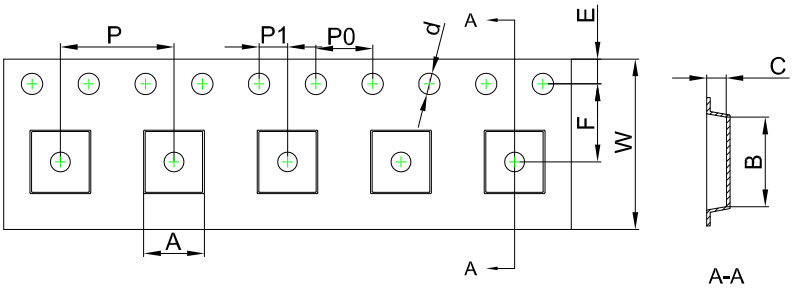


Notes：
1 Controlling dimension：in millimeters.
2 General tolerance:±0.05mm.
2 The pad layout is for referance purpose only.

NOTICE

SZCJ reservesthe right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein.SZCJ does not assume any liability arising out of the application or use of any product described herein.

PDFNWB3.3×3.3-8L Embossed Carrier Tape

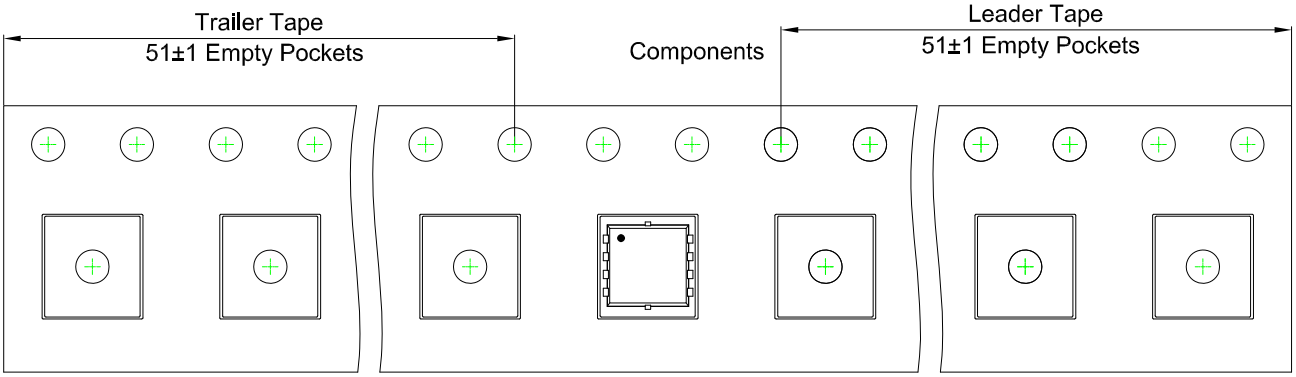


Packaging Description:

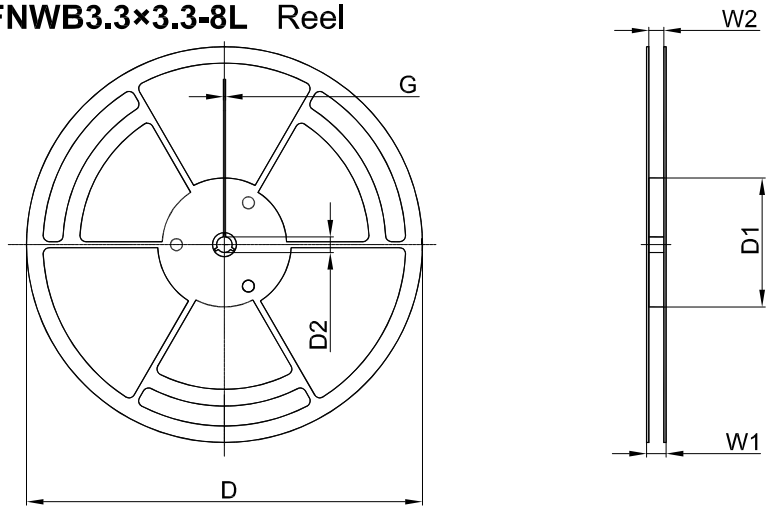
PDFNWB3.3x3.3-8L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFNWB3.3×3.3-8L	3.55	3.55	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

PDFNWB3.3×3.3-8L Tape Leader and Trailer



PDFNWB3.3×3.3-8L Reel



Dimensions are in millimeter						
Reel Option	**D**	**D1**	**D2**	**G**	**W1**	**W2**
13" Dia	φ330.00	100.00	13.00	1.90	17.60	12.40

Reel	Reel Size	Box	Box Size (mm)	Carton	Carton Size (mm)
5,000 pcs	13 inch	10,000 pcs	360×360×65	50,000 pcs	378×358×382

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